

Date Mailed: January 8, 2002

Sheet 1 of 1

#3

FORM 1449*		Docket Number: 10873.830US01	Application Number: 10/002,913
O I P E INFORMATION DISCLOSURE STATEMENT IN AN APPLICATION (Use several sheets if necessary)		Applicant: KITABATAKE	
		Filing Date: October 23, 2001	Group Art Unit: Unknown

U.S. PATENT DOCUMENTS						
EXAMINER INITIAL	DOCUMENT NO.	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
PW	5,915,179	June 1999	Etou et al.			→
FOREIGN PATENT DOCUMENTS						
	DOCUMENT NO.	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION
PW	9-55507	Feb. 1997	Japan			YES NO
						See IDS
OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)						
		"SiC Integrated MOSFETs" by S. Onda et al., Phys. Stat. Sol. (a), Vol. 162, pp. 369-388, 1997				



EXAMINER	<i>Tetsuji Kubota</i>	DATE CONSIDERED	<i>1/8/02</i>
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EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; draw line through citation if not in conformance and not considered. Include copy of this form for next communication to the Applicant.